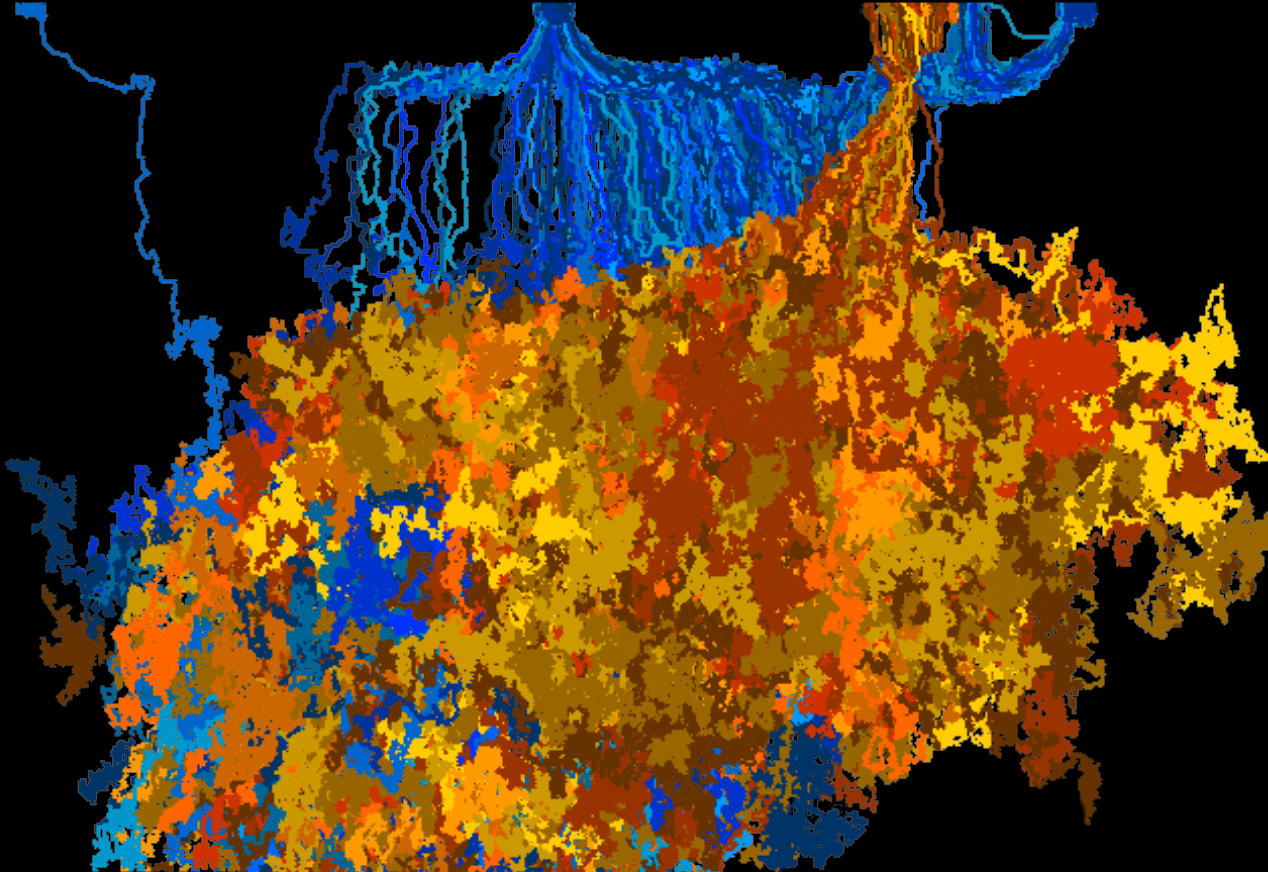




<https://www.desy.de/>

# Allpix Squared 2.x

An Introduction to the Framework & Overview of Series-2.x Features



**Simon Spannagel, DESY**  
for the Allpix Squared Authors

4<sup>th</sup> Allpix Squared User Workshop  
DESY, Hamburg  
22 May 2023

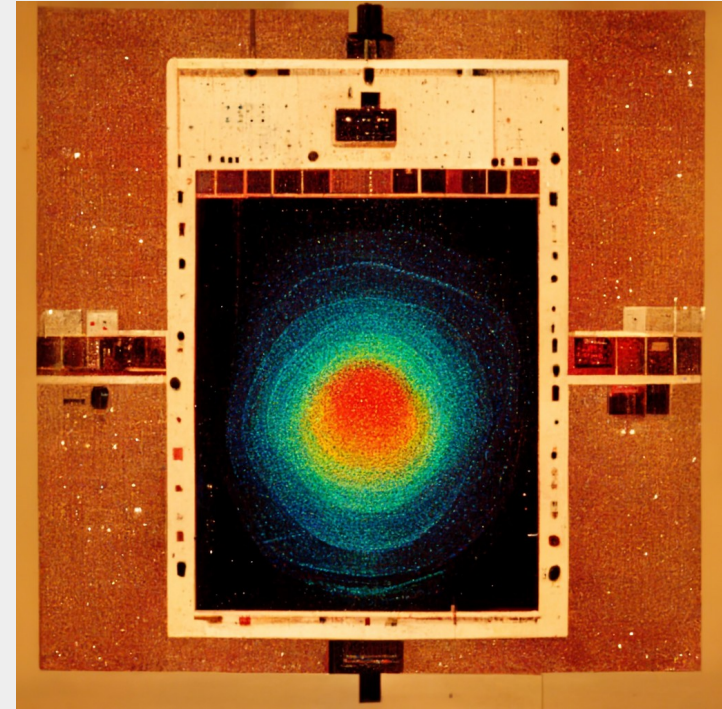
Mohamed Moanis Ali, GSOC2019 Student  
Mathieu Benoit, ORNL  
Thomas Billoud, Université de Montréal  
Tobias Bisanz, CERN  
Marco Bomben, Université de Paris  
Koen van den Brandt, Nikhef  
Carsten Daniel Burgard, DESY  
Maximilian Felix Caspar, DESY  
Liejian Chen, IHEP Beijing  
Dominik Dannheim, CERN  
Manuel Alejandro Del Rio Viera, DESY  
Katharina Dort, University of Gießen  
Neal Gauvin, Université de Genève  
Lennart Huth, DESY  
Daniel Hynds, University of Oxford  
Francisco-Jose Iguaz-Gutierrez, Synchrotron SOLEIL  
Maoqiang Jing, IHEP Beijing  
Moritz Kiehn, Université de Genève

Rafaella Eleni Kotitsa, Université de Genève  
Stephan Lachnit, DESY  
Salman Maqbool, CERN Summer Student  
Stefano Mersi, CERN  
Ryuji Moriya, CERN Summer Student  
Sebastien Murphy, ETHZ  
Andreas Matthias Nürnberg, DESY  
Sebastian Pape, TU Dortmund University  
Marko Petric, CERN  
Florian Michael Pitters, HEPHY  
Radek Privara, Palacky University Olomouc  
Nashad Rahman, The Ohio State University  
Sabita Rao, GSDocs2020 Student  
Daniil Rastorguev, DESY  
Edoardo Rossi, DESY  
Jihad Saidi, Université de Genève  
Andre Sailer, CERN

Tasneem Saleem, Synchrotron SOLEIL  
Arka Santra, Weizman Institute  
Enrico Jr. Schioppa, Unisalento and INFN Lecce  
Sebastian Schmidt, FAU Erlangen  
Paul Schütze, DESY  
Sanchit Sharma, Kansas State University  
Xin Shi, Institute of High Energy Physics Beijing  
Petr Smolyanskiy, Czech Technical University Prague  
Viktor Sonesten, GSOC2018 Student  
Simon Spannagel, DESY  
Reem Taibah, Université de Paris  
Ondrej Theiner, Charles University  
Annika Vauth, University of Hamburg  
Mateus Vicente Barreto Pinto, Université de Genève  
Håkan Wennlöf, DESY  
Andy Wharton, Lancaster University  
Morag Williams, University of Glasgow  
Koen Wolters

# Monte Carlo Simulations of Semiconductor Detectors

- Using Monte Carlo methods to describe detector response is not new
- Creation & proliferation of many different codes for detector simulation:
  - Experiment-specific
  - Specialized on specific detectors
  - Inclusion only of effects relevant to that one simulation
  - Written as part of a PhD thesis, abandoned afterwards
- **Wanted:**  
flexible, tested & supported MC simulation software...



Midjourney,  
/image a silicon pixel detector  
measuring high-energetic particles

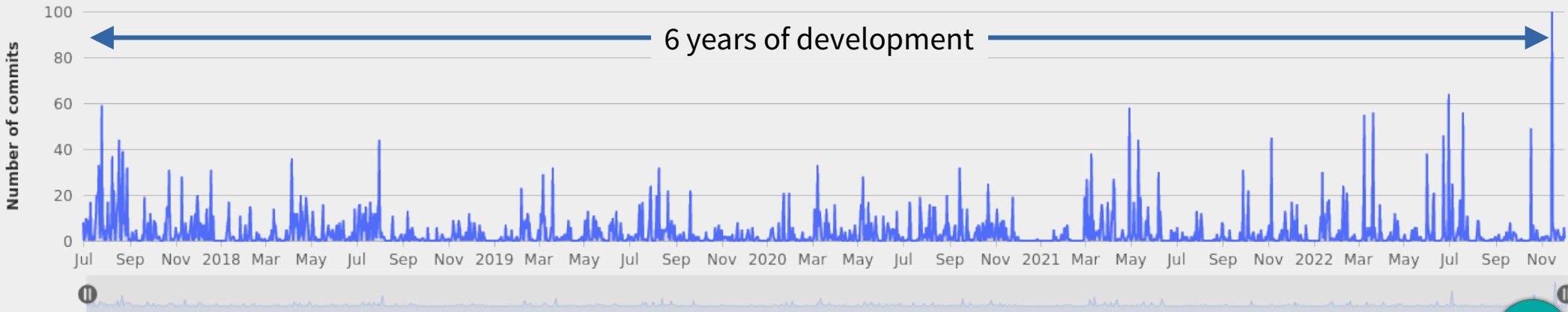
# The Allpix<sup>2</sup> Framework



- Development of entirely new framework
- Now 6 years of development with
  - 46 releases, current version 3.0.0
  - 4 user workshops
  - > 50 code contributors

Development based on four principles:

- I. Integration of Existing Toolkits
- II. Well-Tested & Validated Algorithms
- III. Low Entry Barrier for New Users
- IV. Clean & Maintainable Code

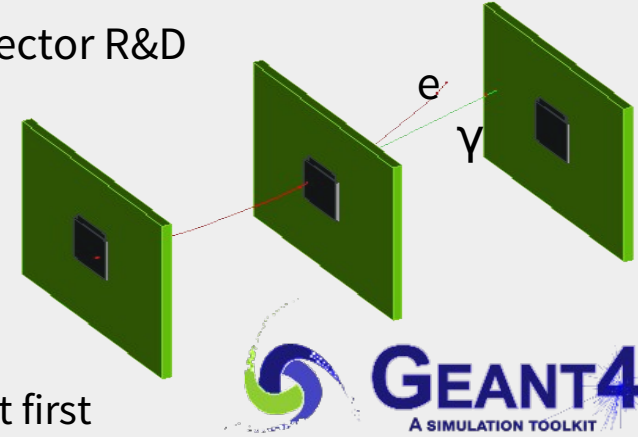


# I. Integration of Existing Toolkits

Many very powerful tools developed and employed over decades of detector R&D  
Leverage their capabilities by providing interfaces for their integration

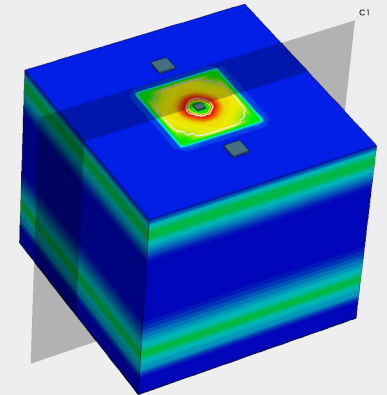
**Geant4** – simulating interactions of particles passing through matter

- Detailed simulation of many interactions & processes
- Cumbersome to use for beginners, complexity often overwhelming at first
- Provide abstraction layer to auto-generate models and run simulation



**TCAD** – solving Poisson's equation using finite element methods

- Detailed understanding of field configuration, sensor behavior
- Tools & knowledge widely spread in community
- Provide possibility to import results to complement MC simulations





# II. Well-Tested & Validated Algorithms

Simulations provide insights into physical processes – but only if they model them correctly!

- Validation of algorithms is a crucial and time-consuming process
- User workshops for exchange of the community, discussions, planning...

- Validating as much as possible against data
- Publishing reference studies including full simulation configuration used
- Providing automated tests for every new feature

Nuclear Inst. and Methods in Physics Research, 4 (2018) 164–172

**Nuclear Inst. and Methods in Physics Research, A**

ALPPIX<sup>2</sup>: modular simulation framework for silicon detectors

S. Spannagel<sup>1,\*</sup>, K. Walden<sup>1,2</sup>, D. Hyde<sup>1,3</sup>, N. Al-Jayeri<sup>1</sup>, M. Rossi<sup>1</sup>, D. Danneberg<sup>1</sup>, N. Gammann<sup>1</sup>, A. Hammer<sup>1,4</sup>, P. Schiller<sup>1</sup>, M. Yeste<sup>1</sup>

1 DESY, 2 DESY, 3 DESY, 4 DESY

ALPPIX<sup>2</sup> is a modular simulation framework for silicon detectors. It is designed to be used for the development of digital detectors for high energy physics experiments. The framework is built on top of the Geant4 simulation framework and provides a high-level interface for the development of digital detectors. It includes a modular architecture that allows for the development of custom detectors and the simulation of their performance. The framework is designed to be used for the development of digital detectors for high energy physics experiments. It includes a modular architecture that allows for the development of custom detectors and the simulation of their performance. The framework is designed to be used for the development of digital detectors for high energy physics experiments. It includes a modular architecture that allows for the development of custom detectors and the simulation of their performance.

ARTICLE INFO

ABSTRACT

1. Introduction

2. Framework architecture

3. Conclusions

Nuclear Inst. and Methods in Physics Research, 4 (2020) 163784

**Nuclear Inst. and Methods in Physics Research, A**

Combining TCAD and Monte Carlo methods to simulate CMOS pixel sensors with a small collection electrode using the Alpex<sup>2</sup> framework

D. Danneberg, K. Dor, D. Hyde<sup>1</sup>, M. Matusik, A. Nürnberg<sup>1</sup>, W. Soosey, S. Spannagel<sup>1</sup>

1 DESY

Combining TCAD and Monte Carlo methods to simulate CMOS pixel sensors with a small collection electrode using the Alpex<sup>2</sup> framework. This paper describes the development of a simulation framework that combines TCAD and Monte Carlo methods to simulate CMOS pixel sensors with a small collection electrode. The framework is designed to be used for the development of digital detectors for high energy physics experiments. It includes a modular architecture that allows for the development of custom detectors and the simulation of their performance. The framework is designed to be used for the development of digital detectors for high energy physics experiments. It includes a modular architecture that allows for the development of custom detectors and the simulation of their performance.

ARTICLE INFO

ABSTRACT

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3. Conclusions

Nuclear Inst. and Methods in Physics Research, 4 (2022) 166491

**Nuclear Inst. and Methods in Physics Research, A**

Transient Monte Carlo simulations for the optimisation and characterisation of monolithic silicon sensors

R. Bahareg<sup>1</sup>, J. Braach<sup>1</sup>, F. Buchmann<sup>1</sup>, M. Carstoph<sup>1</sup>, D. Danneberg<sup>1</sup>, K. Dor<sup>1</sup>, J. Böh<sup>1</sup>, J. Krennath<sup>1</sup>, J. Krüger<sup>1</sup>, J. Linsen<sup>1</sup>, M. Matusik<sup>1</sup>, P. Schiller<sup>1</sup>, W. Soosey<sup>1</sup>, S. Spannagel<sup>1</sup>, T. Voss<sup>1</sup>

1 DESY

Transient Monte Carlo simulations for the optimisation and characterisation of monolithic silicon sensors. This paper describes the development of a simulation framework that combines TCAD and Monte Carlo methods to simulate CMOS pixel sensors with a small collection electrode. The framework is designed to be used for the development of digital detectors for high energy physics experiments. It includes a modular architecture that allows for the development of custom detectors and the simulation of their performance. The framework is designed to be used for the development of digital detectors for high energy physics experiments. It includes a modular architecture that allows for the development of custom detectors and the simulation of their performance.

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JINST

Proceedings of the 17th International Conference on Position Sensitive Detectors

17th International Conference on Position Sensitive Detectors

17-17 September 2022

17-17 September 2022

17-17 September 2022

ALPPIX<sup>2</sup> – silicon detector Monte Carlo simulations for particle physics and beyond

S. Spannagel<sup>1</sup> & P. Schiller

1 DESY

ALPPIX<sup>2</sup> – silicon detector Monte Carlo simulations for particle physics and beyond. This paper describes the development of a simulation framework that combines TCAD and Monte Carlo methods to simulate CMOS pixel sensors with a small collection electrode. The framework is designed to be used for the development of digital detectors for high energy physics experiments. It includes a modular architecture that allows for the development of custom detectors and the simulation of their performance. The framework is designed to be used for the development of digital detectors for high energy physics experiments. It includes a modular architecture that allows for the development of custom detectors and the simulation of their performance.

ARTICLE INFO

ABSTRACT

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ALPPIX<sup>2</sup>: Recent Developments and Applications

S. Spannagel<sup>1</sup>, T. Bissel<sup>1</sup>, K. Walden<sup>1</sup>, N. Gammann<sup>1</sup>, M. Rossi<sup>1</sup>, D. Danneberg<sup>1</sup>, N. Al-Jayeri<sup>1</sup>, M. Rossi<sup>1</sup>, D. Danneberg<sup>1</sup>, N. Gammann<sup>1</sup>, A. Hammer<sup>1</sup>, P. Schiller<sup>1</sup>, M. Yeste<sup>1</sup>

1 DESY

ALPPIX<sup>2</sup>: Recent Developments and Applications. This paper describes the development of a simulation framework that combines TCAD and Monte Carlo methods to simulate CMOS pixel sensors with a small collection electrode. The framework is designed to be used for the development of digital detectors for high energy physics experiments. It includes a modular architecture that allows for the development of custom detectors and the simulation of their performance. The framework is designed to be used for the development of digital detectors for high energy physics experiments. It includes a modular architecture that allows for the development of custom detectors and the simulation of their performance.

ARTICLE INFO

ABSTRACT

1. Introduction

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NIMA 901 (2018) 164 – 172  
doi:10.1016/j.nima.2018.06.020

NIMA 964 (2020) 163784  
doi:10.1016/j.nima.2020.163784

NIMA 1031 (2022) 166491  
doi:10.1016/j.nima.2022.166491

JINST 17 (2022) C09024  
doi:10.1088/1748-0221/17/09/C09024

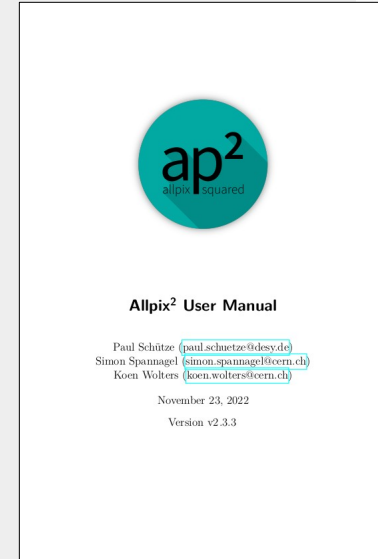
In preparation...



# III. Low Entry Barrier for New Users

Simulation frameworks often very complex:

- complex code base, lack of documentation
- many physical effects to be simulated
- Allpix Squared attempts to facilitate quick starts:
  - Extensive documentation / [user manual](#)
  - [Public forum](#) for help & exchange
  - Human-readable configuration files
  - Support for physical units
  - No coding or code-reading required
- Successfully used e.g. in university education, summer schools, ...



```
1 [AllPix]
2 log_level = "INFO"
3 number_of_events = 500000
4 detectors_file = "telescope.conf"
```

```
[GeometryBuilderGeant4]
world_material = "air"
```

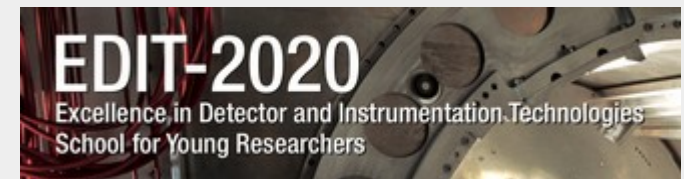
```
[DepositionGeant4]
physics_list = FTTP_BERT_LIV
particle_type = "Pi+"
number_of_particles = 1
beam_energy = 120GeV
# ...
```

```
[ElectricFieldReader]
model="linear"
bias_voltage=150V
depletion_voltage=50V
```

```
21 [GenericPropagation]
22 temperature = 293K
23 charge_per_step = 10
24 spatial_precision = 0.0025um
25 timestep_max = 0.5ns
26
27 [SimpleTransfer]
```



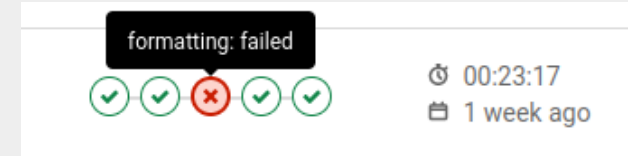
Bonn-Cologne Graduate School  
of Physics and Astronomy





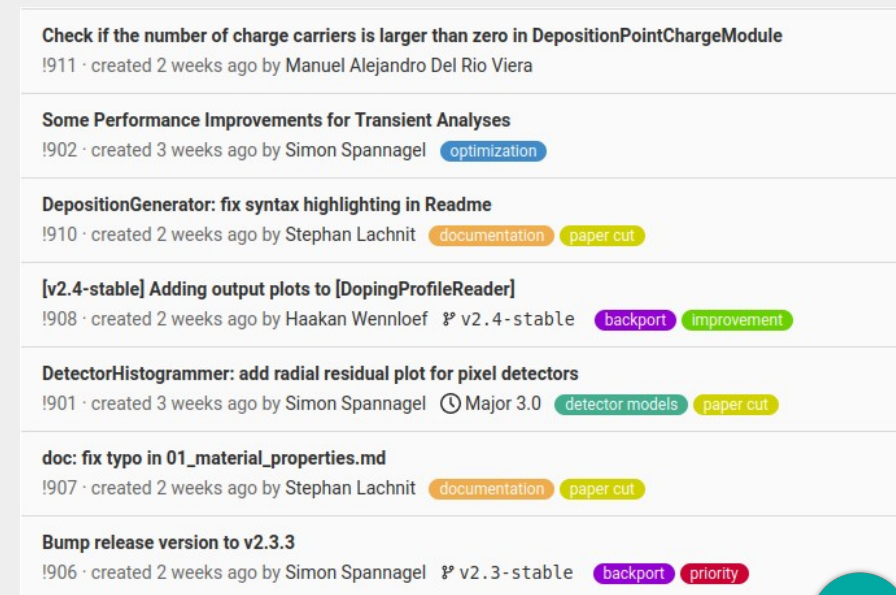
# IV. Clean & Maintainable Code

Collaborative software development requires well-defined procedures –  
 Otherwise quickly becomes unmaintainable

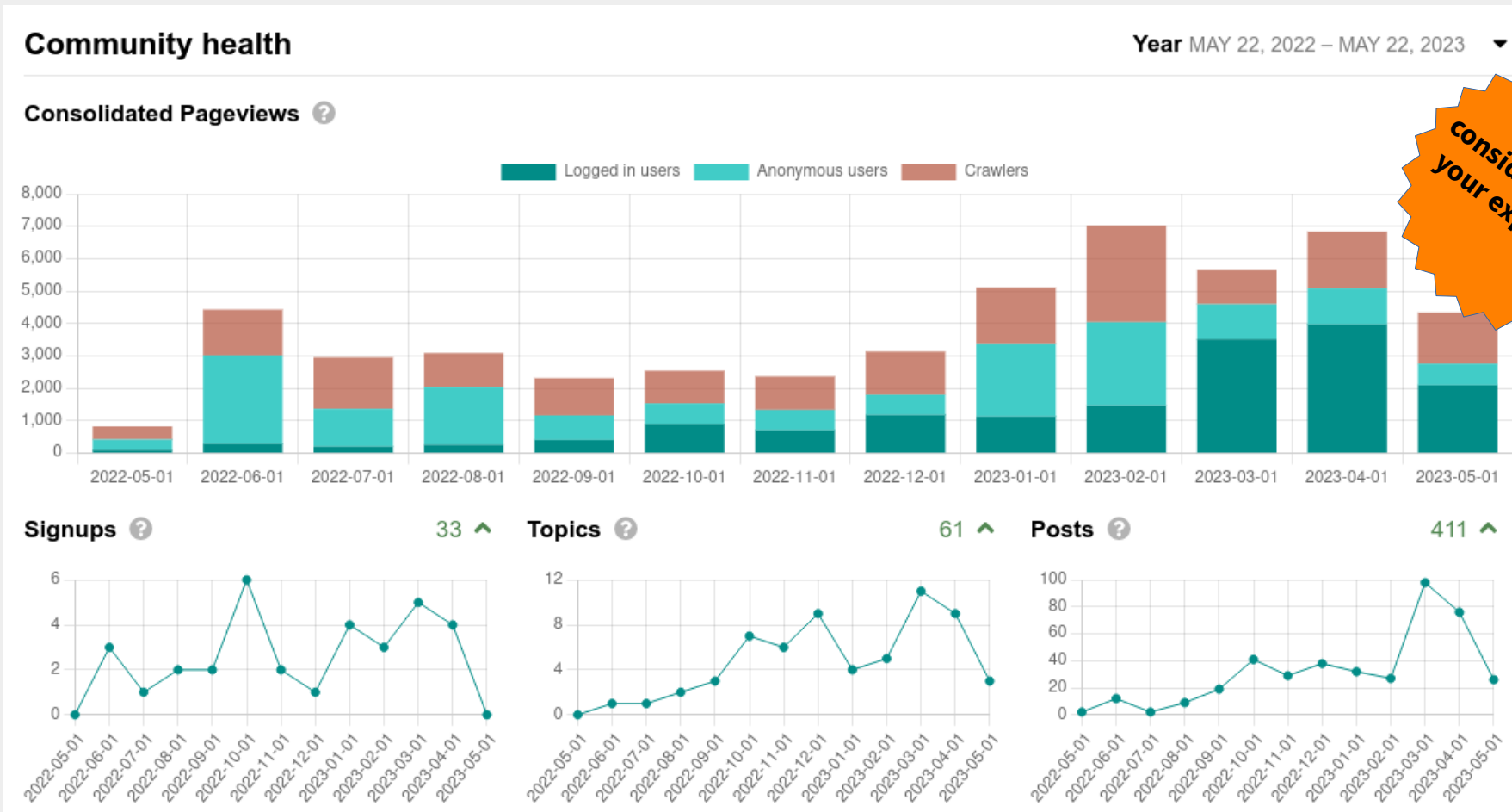


Allpix Squared implements *best practices* for software development

- Permissive MIT open-source license
- Semantic versioning (major.feature.patch)
- Extensive code reviews via merge requests
- Strict enforcement of coding conventions & formatting
- Regular static code analysis
- Following C++17 Standards



# “Community Health” – the APSQ Forum



# Ongoing Developments and Recent Features

```
Module {
    ~Module() = delete;
}

class ModuleManager;
class Messenger;

// Base constructor for unique modules
// param config Configuration for this module
Module(ModuleManager& manager, Configuration& config);
Module(Configuration& config);

// Base constructor for detector modules
// param config Configuration for this module
// param detector Detector bound to this module
// Note: Detector modules should not forget to forward their detector to the base class
// \ref InvalidModuleStateException will be raised if the module failed to do so
Module(Configuration& config, std::shared_ptr<Detector> detector);

// virtual destructor.
// Note: This destructor has all delegates linked to this module
Module::~Module();

// Note: Copying a module is not allowed
Module(const Module&) = delete;
Module(const Module&) const = delete;

// Note: This destructor has delete behaviour (not possible with references)
Module&& operator=(const Module&) = delete;
Module&& operator=(const Module&) const = delete;
```



# Release of Allpix Squared 2.3

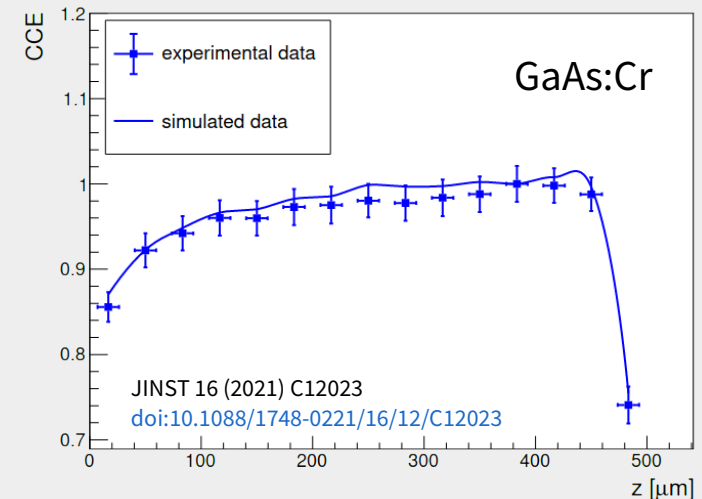
- Released on 16/05/2022, three subsequent patch releases
- Support for Semiconductor Sensor Materials
  - Silicon, Gallium Arsenide, Germanium, Cadmium Telluride, CdZnTe, Diamond, Silicon Carbide
  - Ionization energy, Fano factors as well as some mobility models provided
  - Dedicated section in user manual detailing materials, entry in FAQ describes procedure to use them as sensor
- SRH Recombination rate now scaling with temperature
- Implementation of “standard” low-fluence models for radiation-damage induced trapping, along with possibility to define custom formula
- Detailed release notes:  
<https://cern.ch/allpix-squared/post/2022-05-16-allpix-squared-2.3-released/>

# Other Semiconductor Sensor Materials

## Allpix<sup>2</sup> Silicon Semiconductor Detector Simulation Framework

- Selection of sensor material in det. model
- Definition of sensor materials impacts ...
  - Material in Geant4 geometry
  - Charge carrier creation energy default
  - Fano factor default
  - Mobility model, recombination, ...
- Benchmark simulation using GaAs:Cr sensors show very good agreement

Material	Charge Creation Energy [eV]	Fano factor	Sources
Silicon	3.64	0.115	[25], [26]
Germanium	2.97	0.112	[27]
Gallium Arsenide	4.2	0.14	[28]
Cadmium Telluride	4.43	0.24	[29], [30]
Cadmium Zinc Telluride Cd <sub>0.8</sub> Zn <sub>0.2</sub> Te	4.6	0.14	[31], [32]
Diamond	13.1	0.382	[33], [33]
Silicon Carbide (4H-SiC)	7.6	0.1	[34], [35]

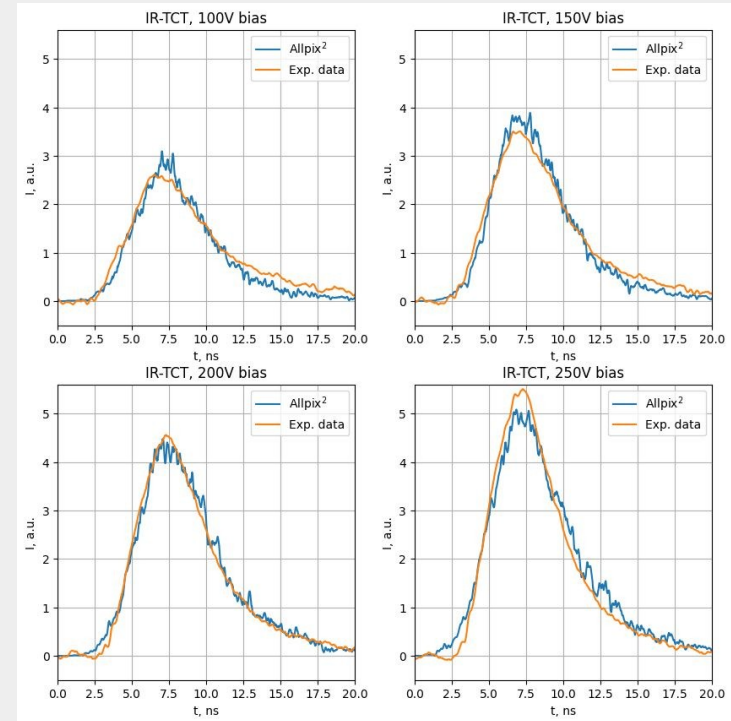
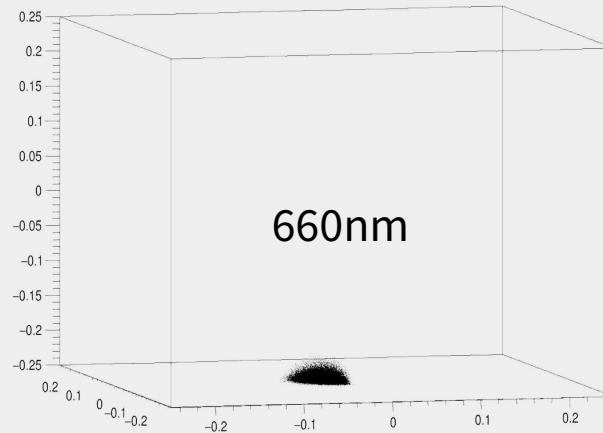
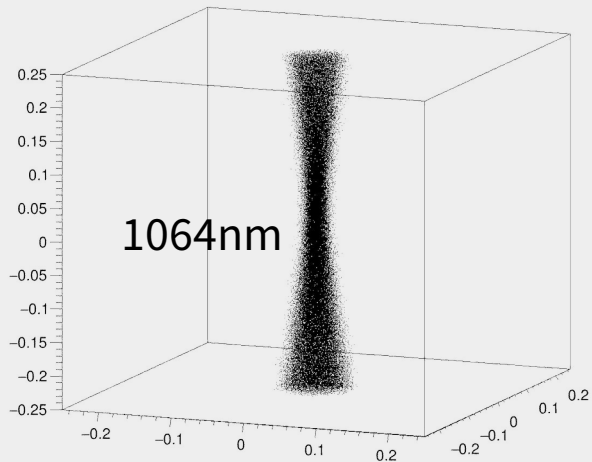


# Release of Allpix Squared 2.4

- Released on 12/01/2023
- New module: DepositionGenerator
  - Module to read primary particles from MC generators sch as Pythia
  - Using Geant4 to propagate through setup
  - Allows easier integration into existing simulation toolchains
- New module: DepositionLaser
  - Module to simulate laser & TCT measurements
  - Includes refraction, focusing, absorption, temporal pulse distribution
- Detailed release notes:  
<https://cern.ch/allpix-squared/post/2023-01-12-allpix-squared-2.4-released/>

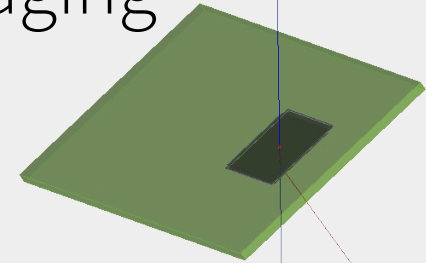
# Simulation of TCT & Lasers

- Simulate interaction of visible/near-IR light with sensors
- Implemented as separate deposition module
- Pulse with individual photons generated over time
- Penetration depth, refraction simulated, different beam geometries & wavelengths possible
- See talk by [Daniil](#)



# Application Examples

MAPS Sensors, PET Scanners, Neutron Imaging



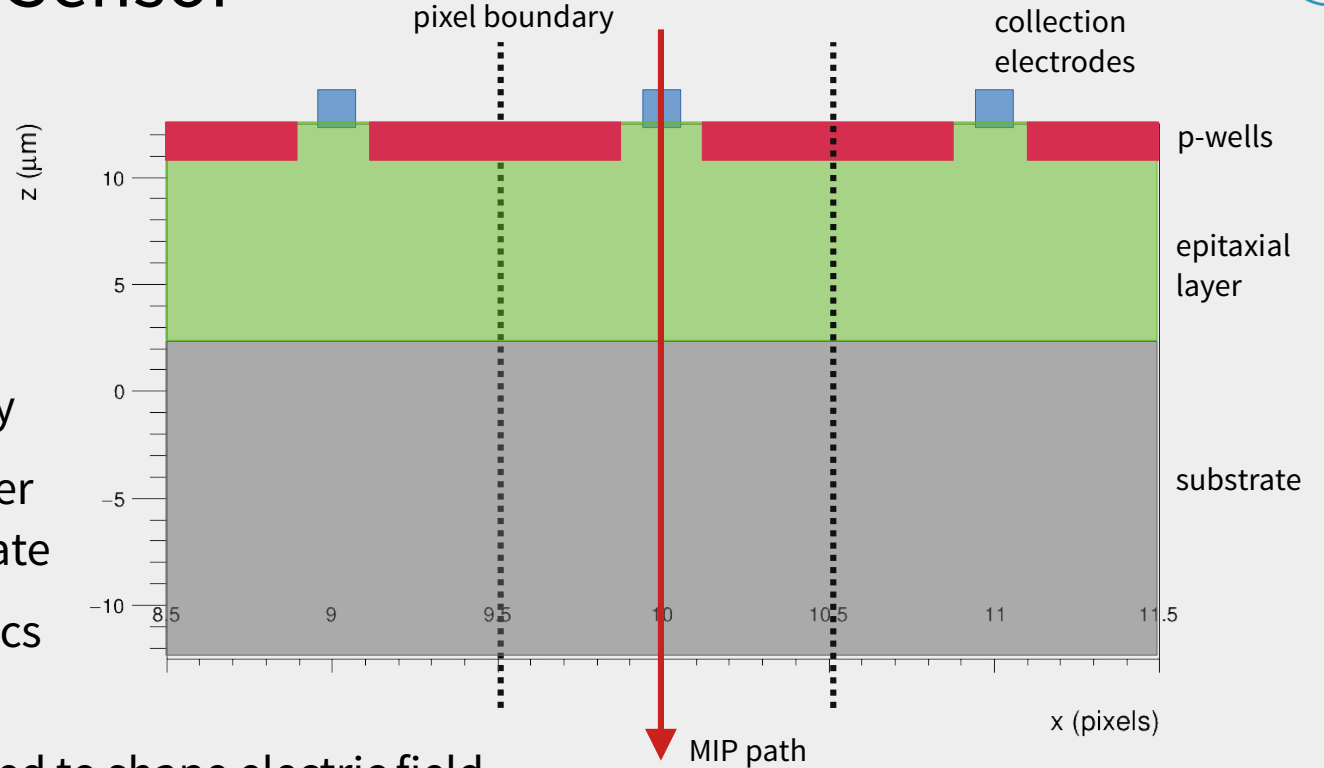


# Simulating a MAPS Sensor

MAPS sensors are complex...

Example:

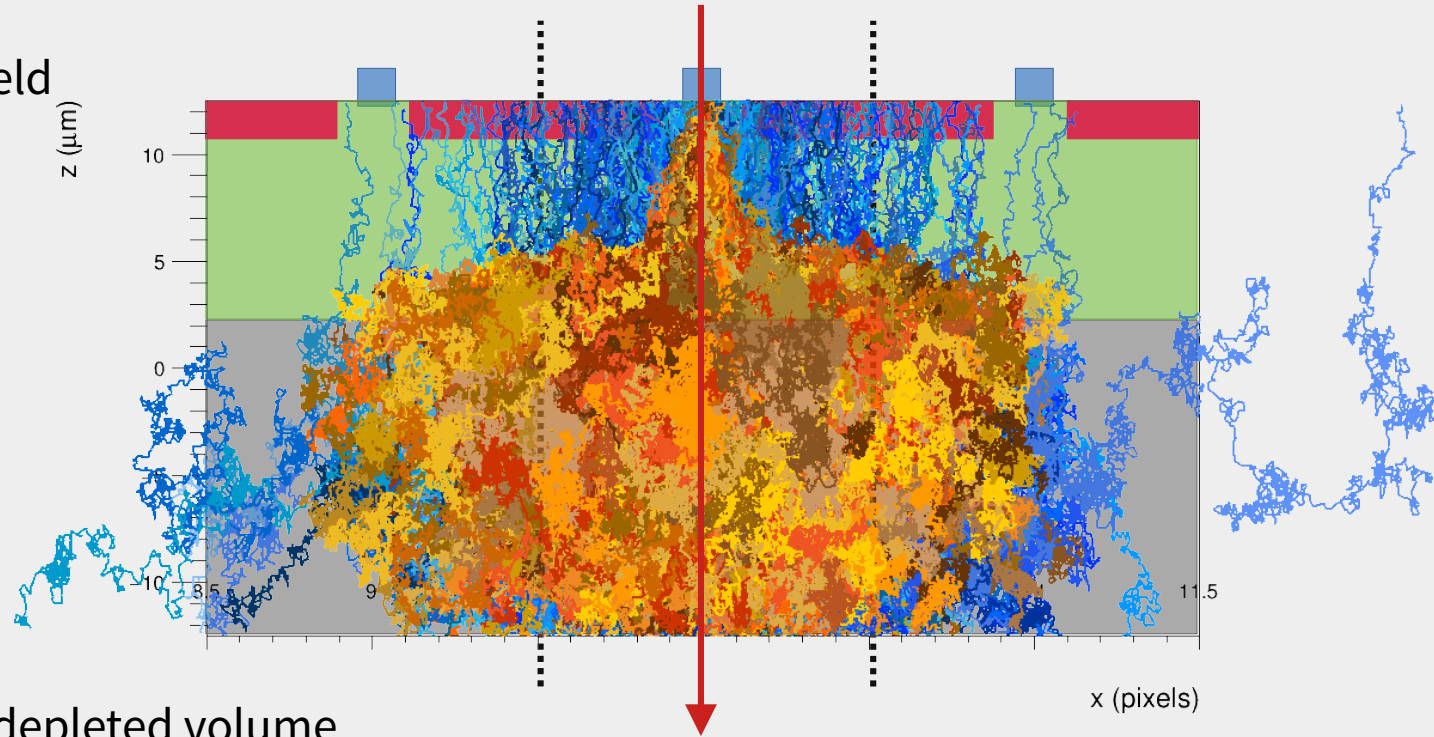
- Small-electrode sensor in CMOS Imaging technology
- High-resistivity epitaxial layer on electronics-grade substrate
- Deep wells protect electronics circuit from sensor field
- Additional implantations used to shape electric field



Simulating response to minimum ionizing particle incident perpendicular to surface

# Simulating a MAPS Sensor – Simplistic Approach

- Applying linear electric field
  - Bias voltage -1.2 V
  - Depletion depth 10  $\mu\text{m}$
- Carrier mobility:
  - Canali model
  - Integrating for 50 ns



- Diffusion dominant in undepleted volume
- Linear drift of charge carriers towards sensor surface, no drift to electrodes
- Large charge cloud, significant signal contribution from substrate

■ electrons  
■ holes

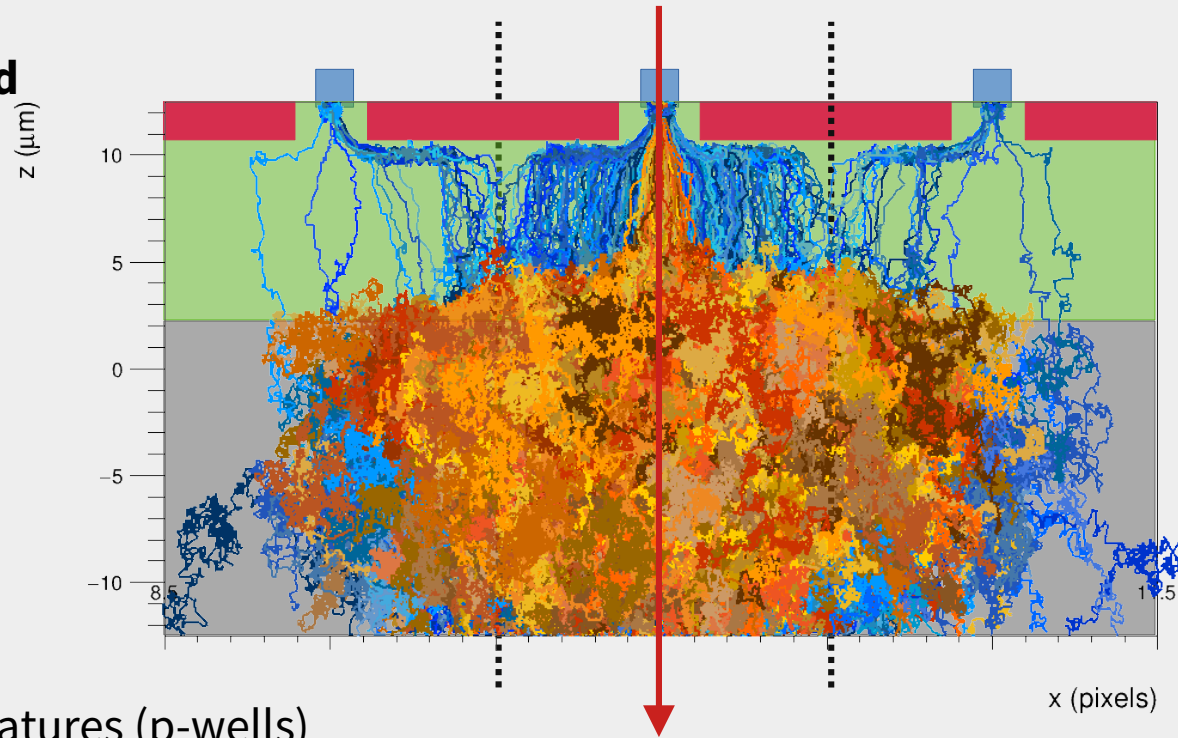
# Simulating a MAPS Sensor – The Electric Field

- Applying **TCAD electric field**

- Bias voltage -1.2 V
- Depletion depth 10  $\mu\text{m}$

- Carrier mobility:

- Canali model
- Integrating for 50 ns

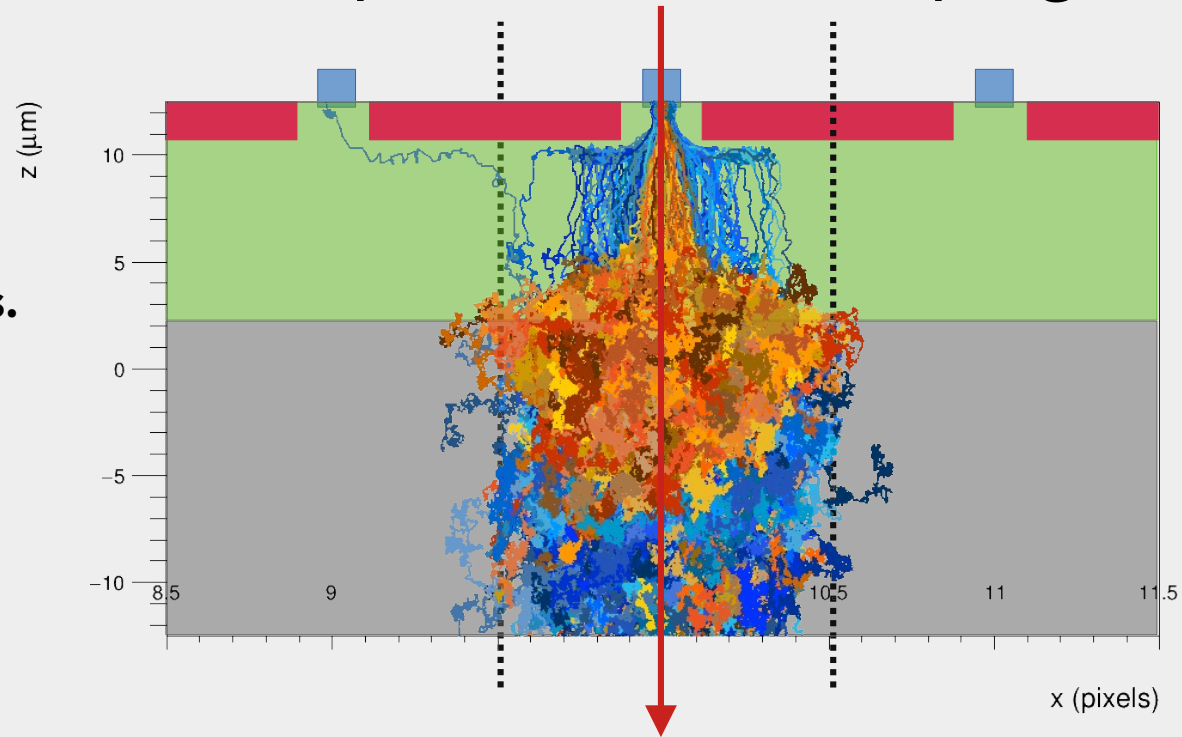


- Carrier drift obeys sensor features (p-wells)
- Collection at electrodes
- Still signal contribution from substrate

■ electrons  
■ holes

# Simulating a MAPS Sensor – Epi & Substrate Doping

- Applying TCAD electric field
  - Bias voltage -1.2 V
  - Depletion depth 10  $\mu\text{m}$
- Setting **doping for epi & subs.**
- Carrier mobility:
  - **Masetti-Canali** model (doping dependent)
  - Integrating for 50 ns

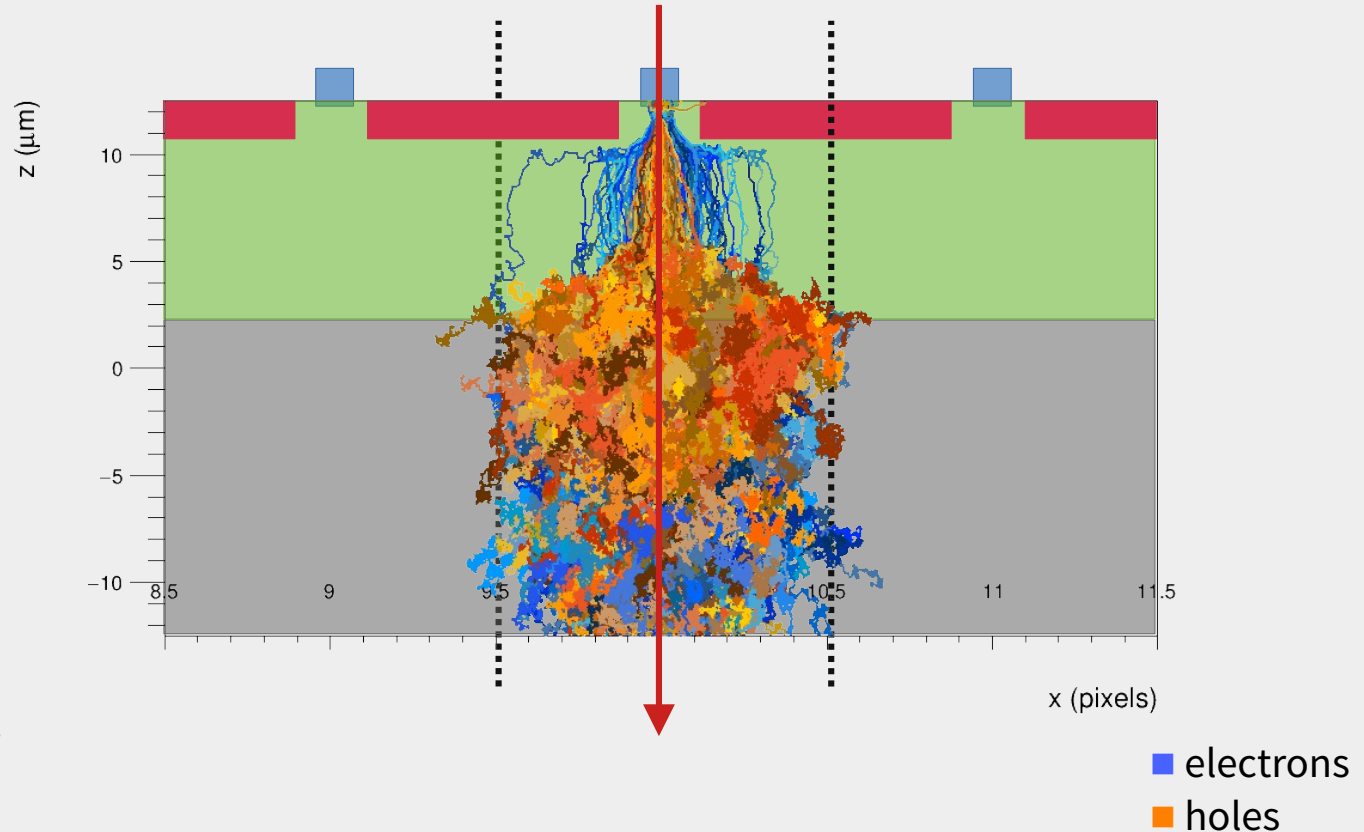


■ electrons  
■ holes

- Significant reduction of diffusion in highly-doped substrate
- Less charge sharing from substrate contributions

# Simulating a MAPS Sensor – Carrier Lifetime

- Applying TCAD electric field
  - Bias voltage -1.2 V
  - Depletion depth 10  $\mu\text{m}$
- Setting doping for epi & subs.
- Carrier mobility:
  - Masetti-Canali model (doping dependent)
  - Integrating for 50 ns
- **Recombination: combined SRH-Auger model**

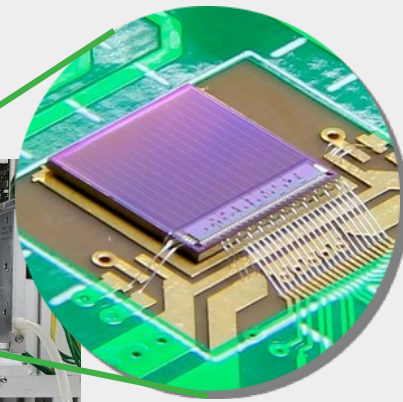
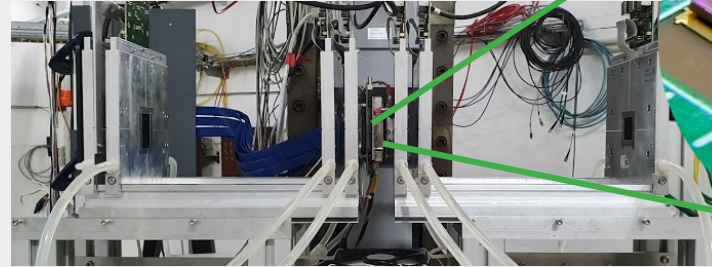


- Significant reduction of substrate contributions due to short lifetime in high-doping volume

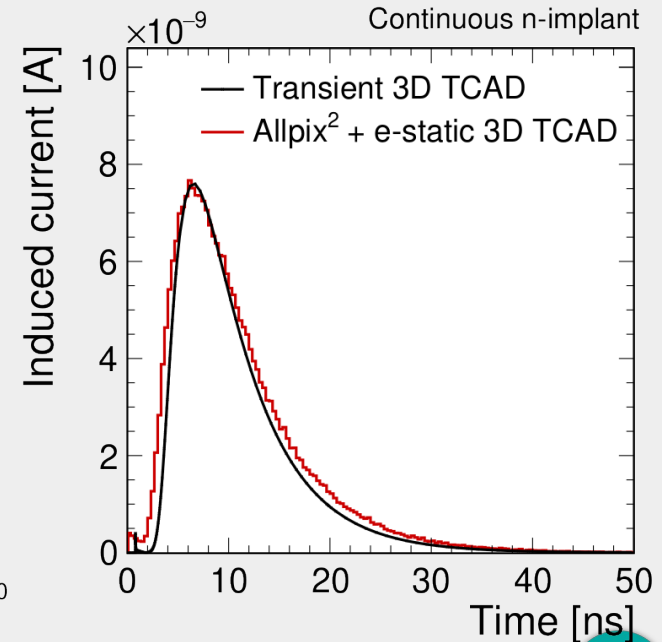
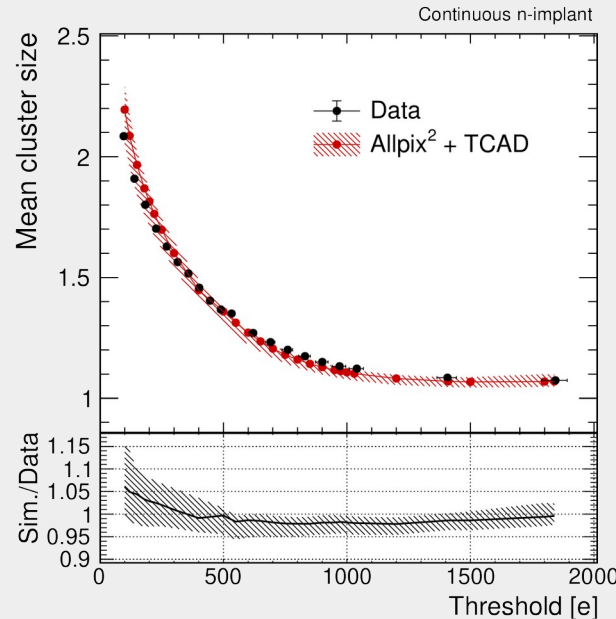
# Comparison with Testbeam Data

NIMA 1031 (2022) 166491  
doi:10.1016/j.nima.2022.166491

- CLICTD prototype for CLICdet tracking detector
- Validation of MC simulation with data recorded at DESY II Testbeam

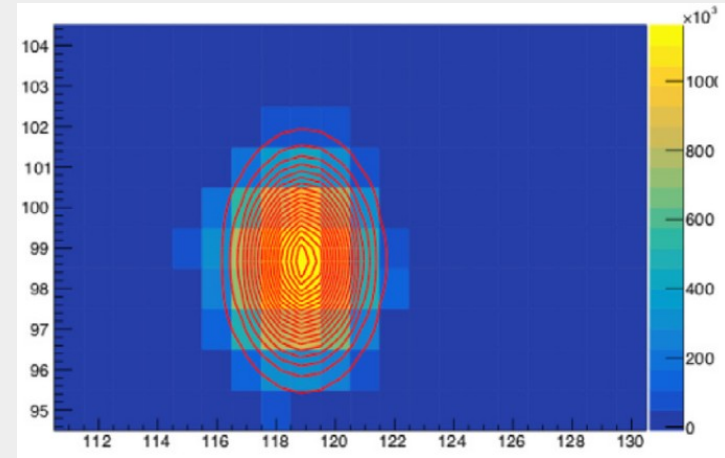


- Excellent match of position resolution as function of threshold
- Comparison of TCAD transient simulation with Shockley-Ramo MC simulation
  - Very good match, also across different sensor designs



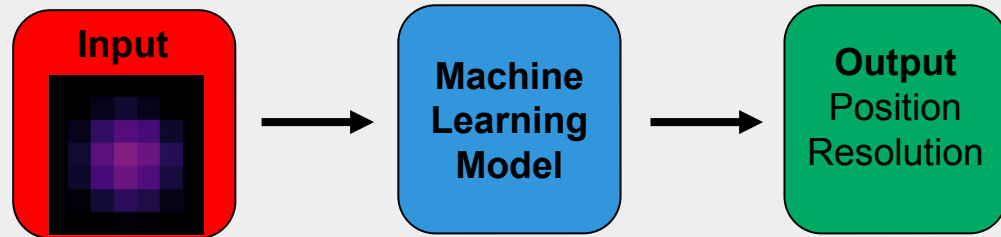
# Machine Learning for Neutron Position Resolution

- High spatial resolution of ultracold neutron (UCN) measurements is crucial for several experiments involving UCNs such as quantum physics and quantum gravity
- Previous work uses a 2D Gaussian fit to determine hit position
- **Goal:** use machine learning and Allpix Squared to predict hit position while accounting for detector physics



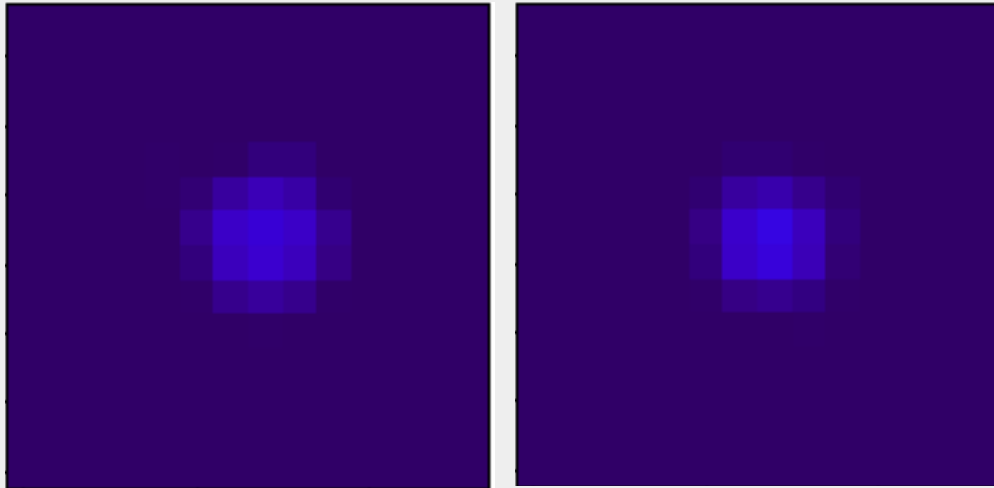
2D gaussian fitted to a UCN hit

NIMA 1003 (2021) 165306  
[doi:10.1016/j.nima.2021.165306](https://doi.org/10.1016/j.nima.2021.165306)

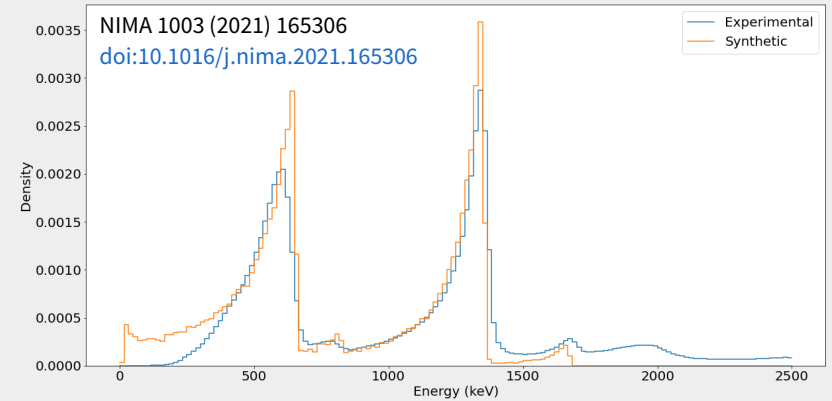


## UCN Hit Images:

Experimental vs Allpix Squared



## Experimental & simulated energy spectra





# Summary

- Very successful development cycle of Allpix Squared 2.x
  - 5 feature releases 2.0 – 2.4, many additional patch releases
  - Many new features & effects added, extended simulation reach
  - Many very interesting applications – some presented in the coming days...
- Lots of development effort went into work towards APSQ 3.0
  - stay tuned for tomorrow!

# Allpix Squared Resources



Website

<https://cern.ch/allpix-squared>



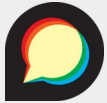
Repository

<https://gitlab.cern.ch/allpix-squared/allpix-squared>



Docker Images

[https://gitlab.cern.ch/allpix-squared/allpix-squared/container\\_registry](https://gitlab.cern.ch/allpix-squared/allpix-squared/container_registry)



User Forum:

<https://cern.ch/allpix-squared-forum/>



Mailing Lists:

allpix-squared-users <https://e-groups.cern.ch/e-groups/Egroup.do?egroupId=10262858>

allpix-squared-developers <https://e-groups.cern.ch/e-groups/Egroup.do?egroupId=10273730>



User Manual:

<https://cern.ch/allpix-squared/usermanual/allpix-manual.pdf>

